

Energy Spread Compensation In BTL

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Sources and Compensation of Energy Spread In BTL

Momentum spread of the beam at the end of the linac is $\sim 2.2 \times 10^{-4}$ r.m.s.

At CDR, the BTL transport and Booster injection were simulated without the space charge.

Space charge doubles the beam momentum spread in BTL to $\sim 4.3 \times 10^{-4}$. The linac energy jitter, specified at 1.5×10^{-4} r.m.s., will effectively increase the momentum/energy spread.

The momentum spread increases the longitudinal emittance of the painted Booster beam and can increase losses at injection and beginning of the acceleration.

A buncher placed in BTL can be used to control the energy spread of the linac beam. The buncher will also reduce the energy jitter.

The injection energy offset and injection phase gate(s) can be optimized to improve injection and reduce losses.

Description of These Simulations

The injection process was simulated without space charge and no buncher, with space charge but without energy spread compensation, and with space charge and buncher

The following locations and frequencies of the buncher were considered:

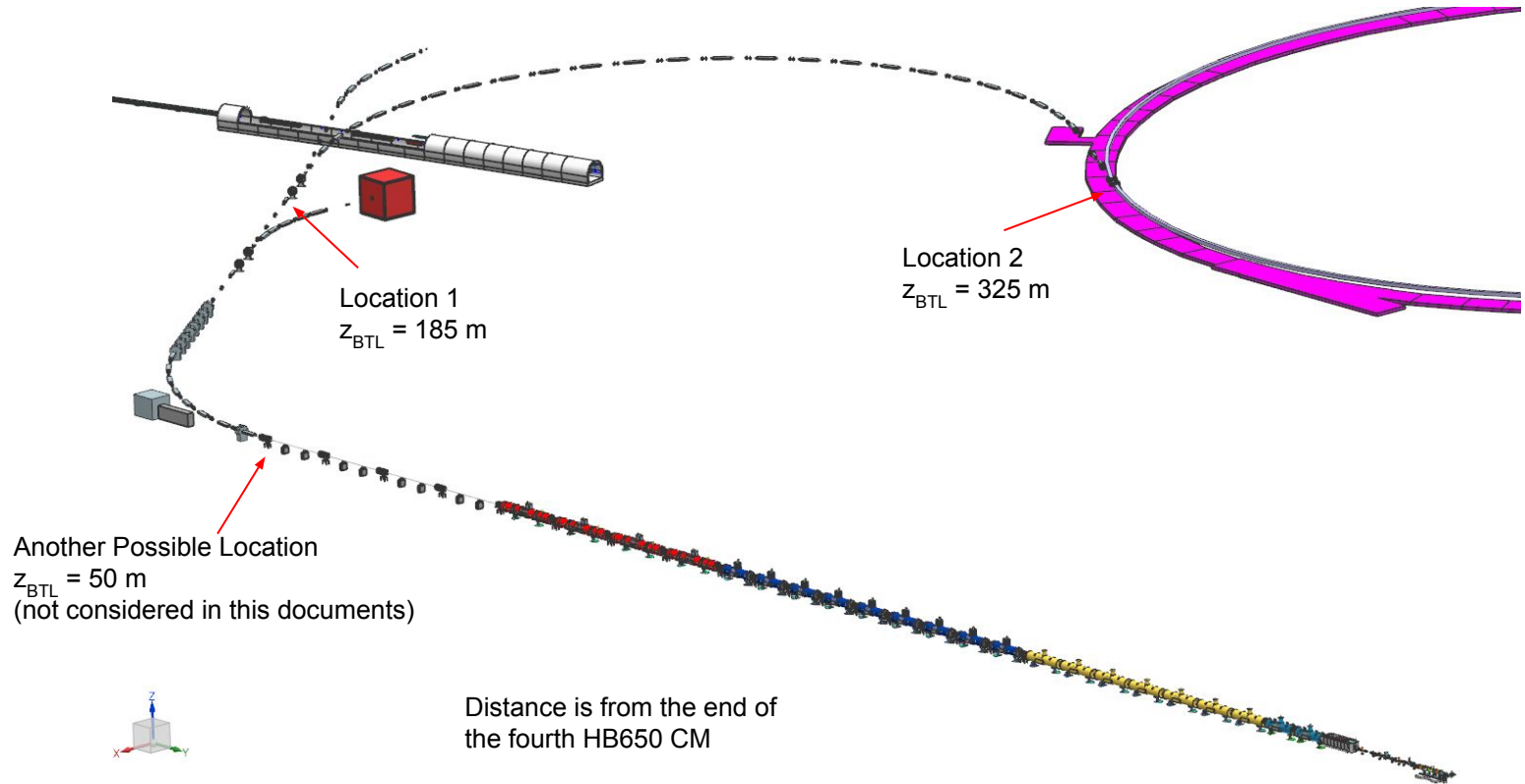
- Buncher located at 185m, cavity frequency 650 MHz
- Buncher located at 325m, cavity frequency 325 MHz

The following injection scenarios were considered (phase is for the Booster bucket)

- Energy offset: $dp/p = 7e-4$, single phase gate: -0.55π to 0.55π
- Energy offset: $dp/p = 0$, two phases gates: -0.65 to -0.1π and 0.1 to 0.65π
- Energy offset: $dp/p = 2e-4$, two phases gates: -0.65π to -0.1π and 0.1π to 0.65π

Random energy jitter of $1.5e-4$ rms was added for cases without buncher. It was set to 0 for cases with a buncher because the buncher reduced the jitter

Linac and BTL Layout with Buncher Options

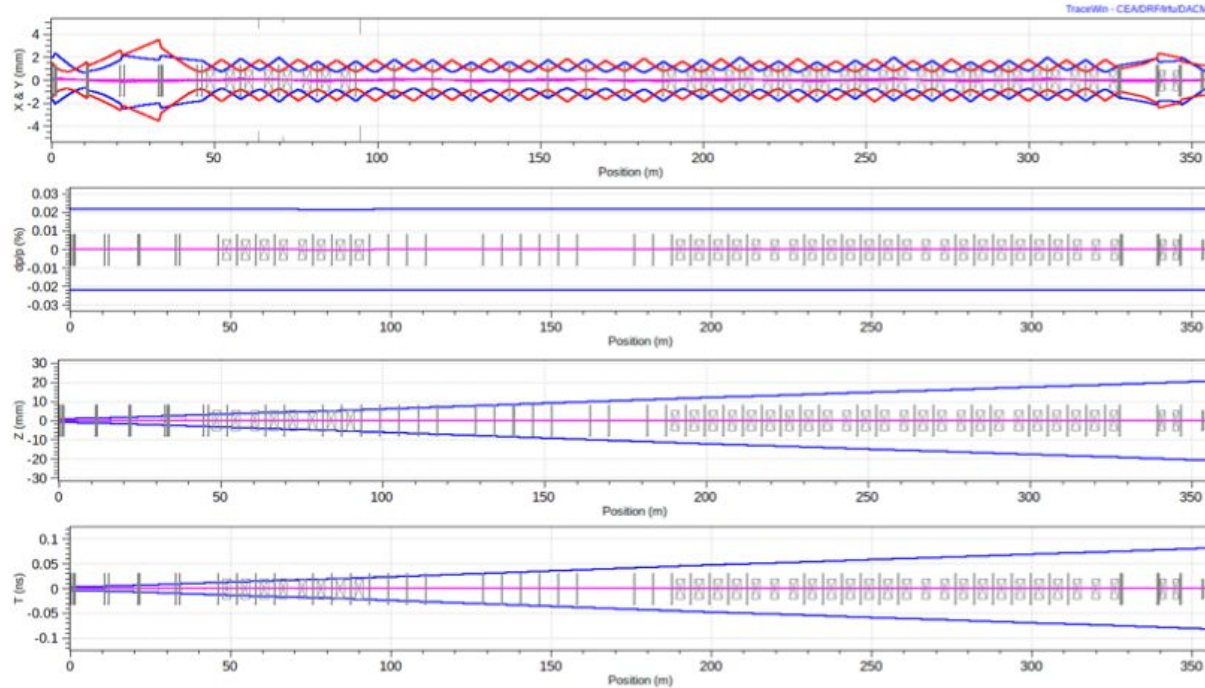


Comments:

This scenario is unrealistic
because it does not include the
space charge

CDR Design: no SC, no buncher

CDR design: No SC, No buncher, beam evolution in BTL

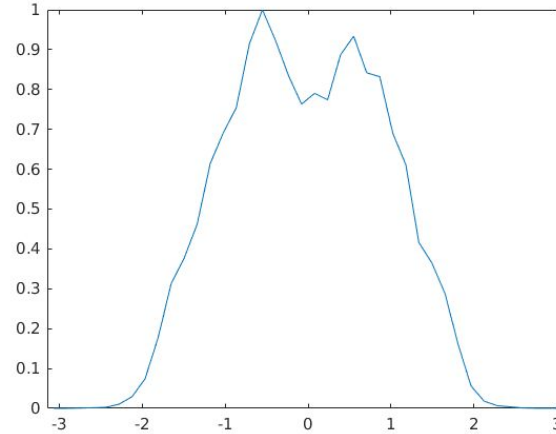
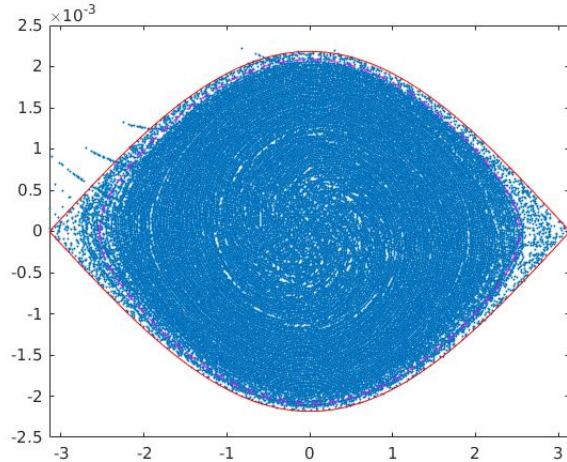


Comments:

This scenario is unrealistic because it does not include the space charge

Momentum spread is constant, $2.16e-4$ (rms)

CDR design: off-energy injection



Linac beam parameters: $\text{std}(dp/p) = 2.1698e-04$, $1.5e-4$ std dp from jitter

Injection parameters: off energy, $dp/p_{inj} = 7e-4$, dp ripple = $1.5e-4$, one gate: -0.55π to $+0.55\pi$

Simulated results:

area of separatrix is 0.076627

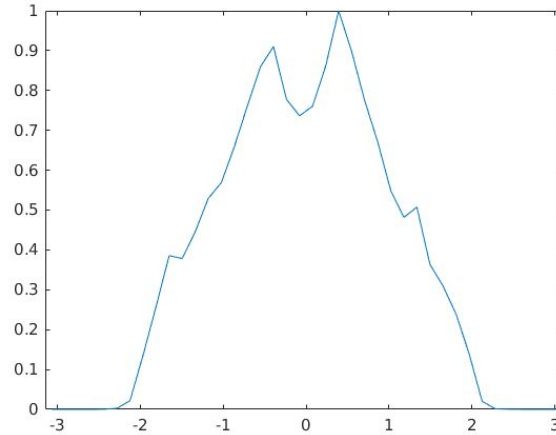
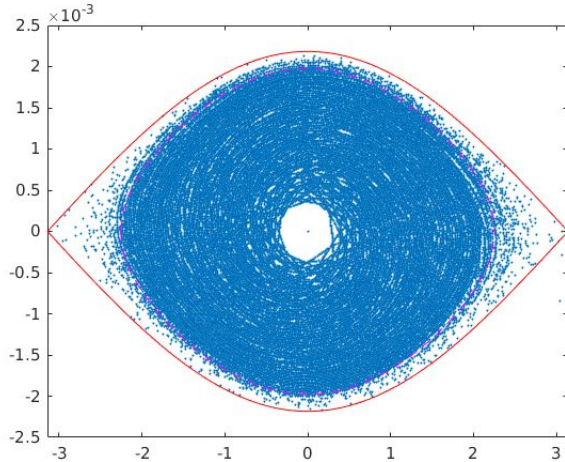
area of the 99.9% of particles is 0.066238, ratio to the separatrix area is 0.864440

phase std 0.910944, energy std 1.046893

lost particles 1836 out of 5410001 injected, ratio is 0.000339

bunching factor 2.560398

CDR design modified: on-energy injection



Linac beam parameters: $\text{std}(dp/p) = 2.1698e-04$, $1.5e-4$ std dp from jitter

Injection parameters: on energy, $dp/p_{inj} = 0.0$, dp ripple = $1.5e-4$,
two gates -0.65π - -0.1π and 0.1π - 0.65π ,

Simulated results:

area of separatrix is 0.076627

area of the 99.9% of particle is 0.057329, ratio to the separatrix area is 0.748169

phase std 0.944689, energy std 1.064908

lost particles 85 out of 5420001 injected, ratio is 0.000016

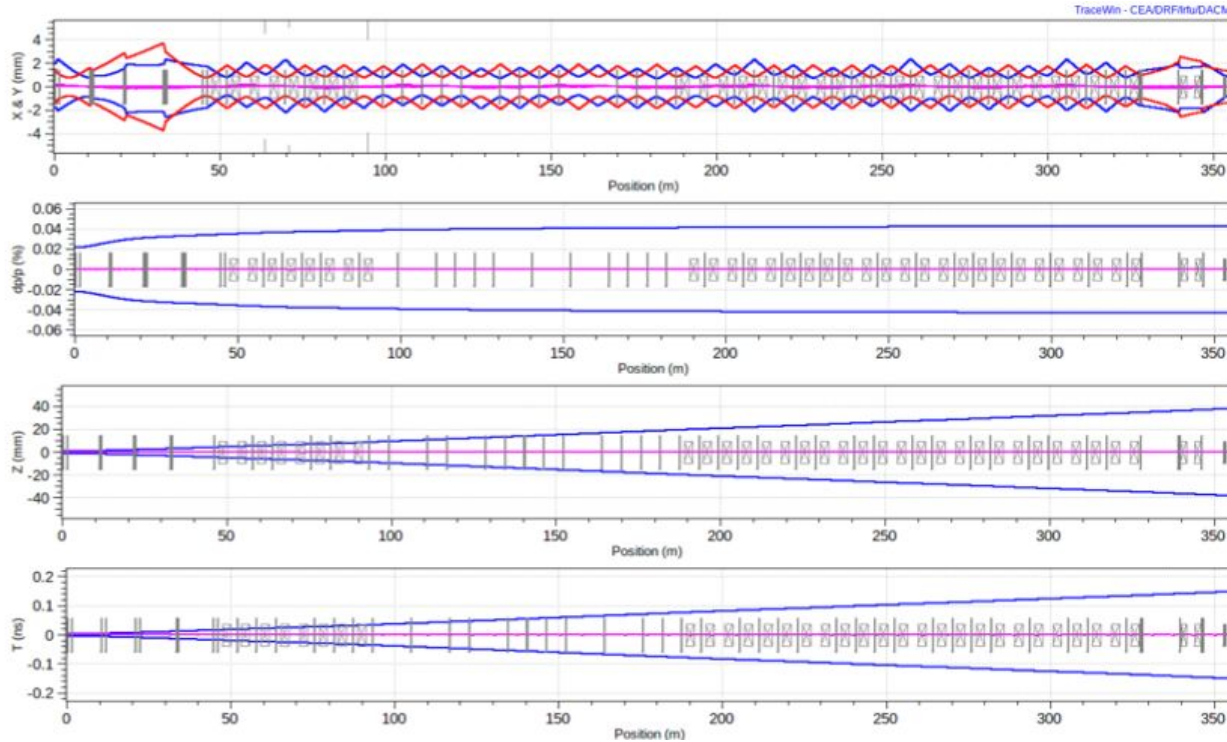
bunching factor 2.665434

Comments:

- On-energy injection with two gates yields smaller emittance and losses and can be beneficial in comparison to the CDR off-energy injection scheme
- On-energy injection increases the number of foil hits by ~50%. This can affect lifetime of the foil.

Simulations with SC but without buncher

Actual Baseline (Dec 2019), With SC, No buncher

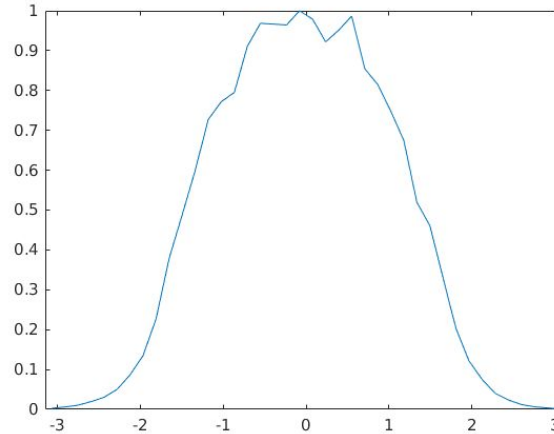
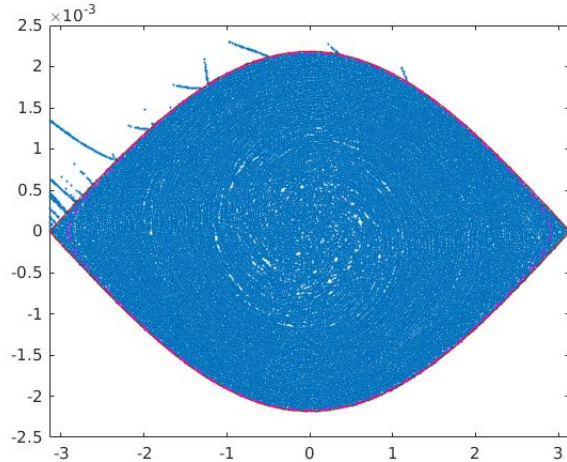


Comments:

This is expected beam dynamics if the energy spread is not compensated

Momentum spread nearly doubles to $4.3e-4$ (rms)

Actual Baseline: with SC, No Buncher: Off-energy Injection



Comments:

The bucket is full, leaving no margin between the beam distribution and separatrix

Linac beam parameters: $\text{std}(p) = 4.3319\text{e-}04$, $1.5\text{e-}4$ $\text{std}(dp/p)$ from jitter

Injection parameters: off energy = $7\text{e-}4$, one gate $-0.55\pi - 0.55$, dp ripple = $1.5\text{e-}4$

Simulated results:

area of separatrix is 0.076627

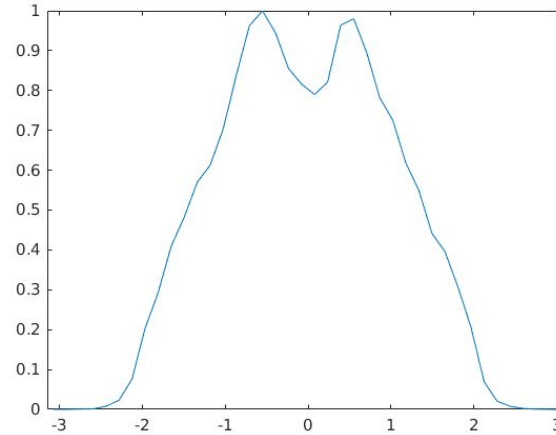
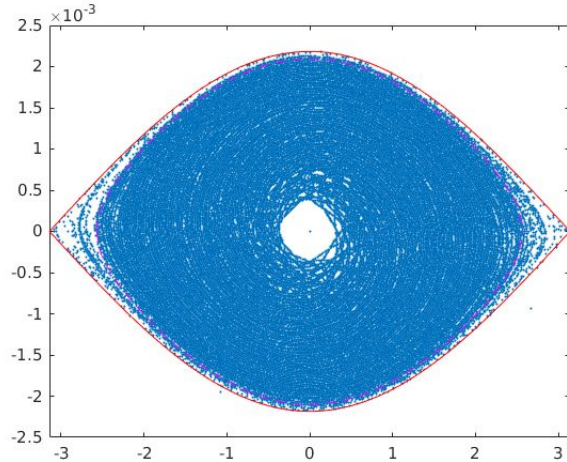
area of the 99.9% of particles is 0.074723, the ratio to the separatrix area is 0.975161

phase std 0.975658, energy std 1.082379

lost particles 33930 out of 5410001 injected, ratio is 0.006272

bunching factor 2.238816

Actual Baseline : with SC, no buncher, on-energy injection



Comments:

The bucket is nearly full, leaving little margin between the beam distribution and separatrix

Linac beam parameters: $\text{std}(p) = 4.3319\text{e-}04$, $1.5\text{e-}4$ $\text{std}(dp/p)$ from jitter

Injection parameters: on energy, $dp/p_{\text{inj}} = 0.0$, dp ripple = $1.5\text{e-}4$, two gates $-0.65\text{Pi} - -0.1\text{Pi}$ and $0.1\text{Pi} - 0.65\text{Pi}$,

Simulated Results:

area of separatrix is 0.076627

area of the 99.9 % of particles is 0.067121, the ratio to the separatrix area is 0.875959

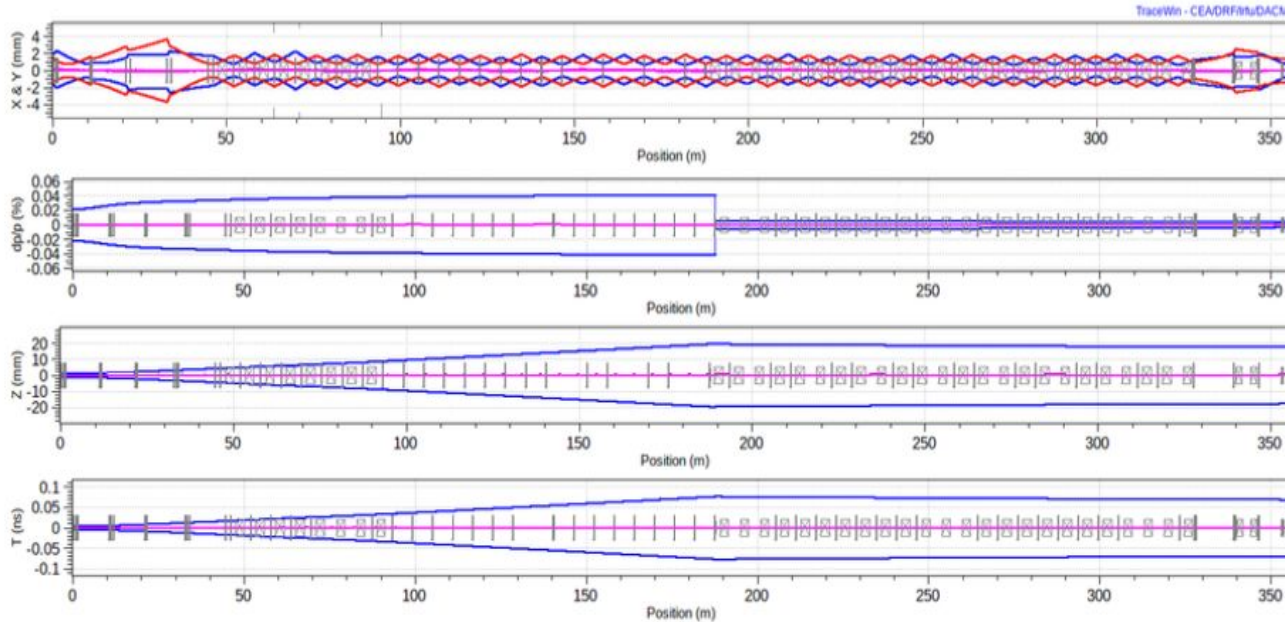
phase std 0.991292, energy std 1.109542

lost particles 520 out of 5420001 injected, ratio is 0.000096

bunching factor 2.302359

With SC and
Buncher at 185 m
(Location 1, middle of BTL),
 $F=650$ MHz, $V=2$ MV

With SC, 650 MHz Buncher at 185 m, 2 MV

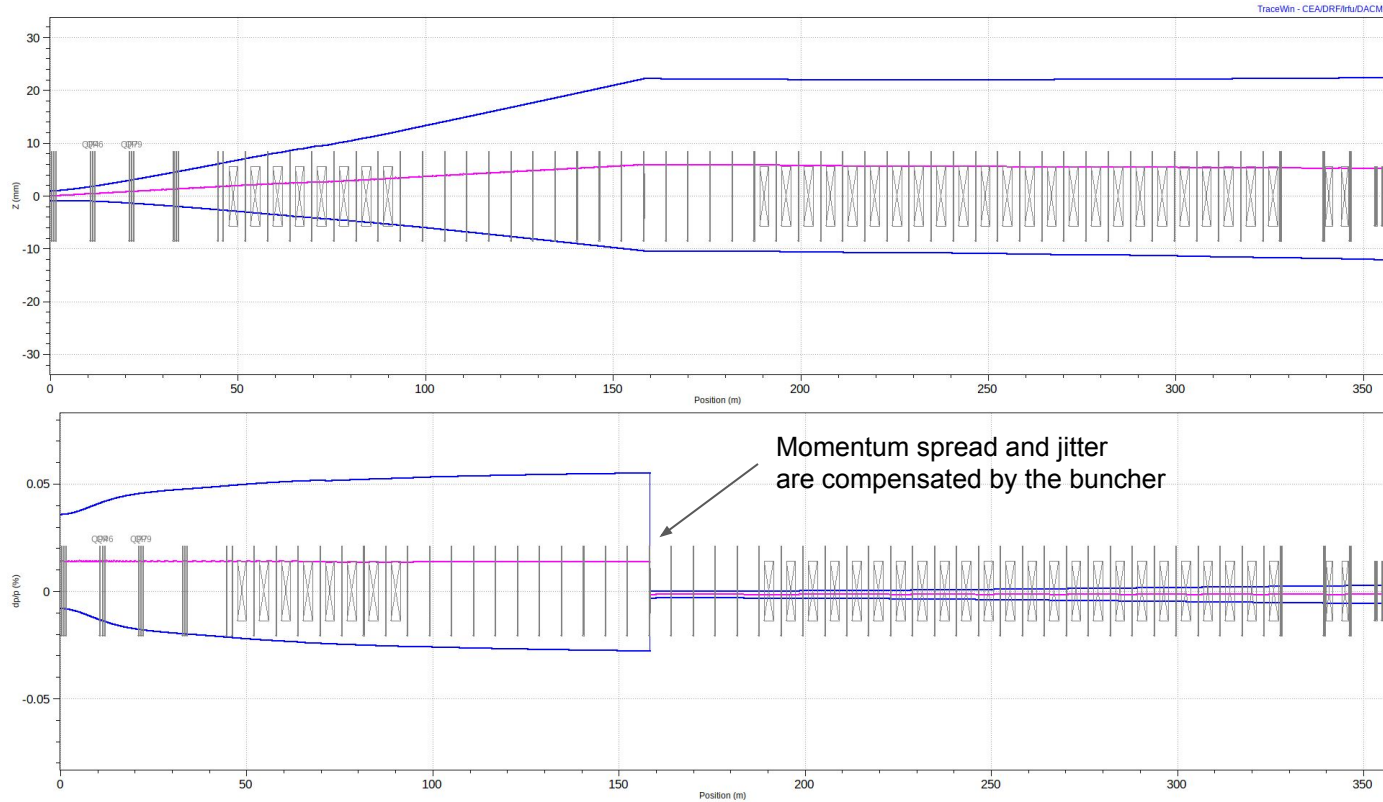


Comments:

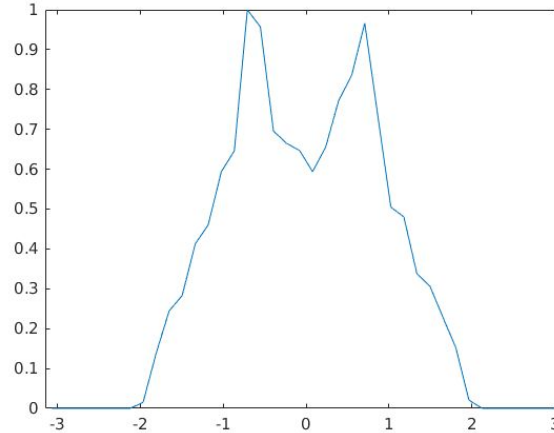
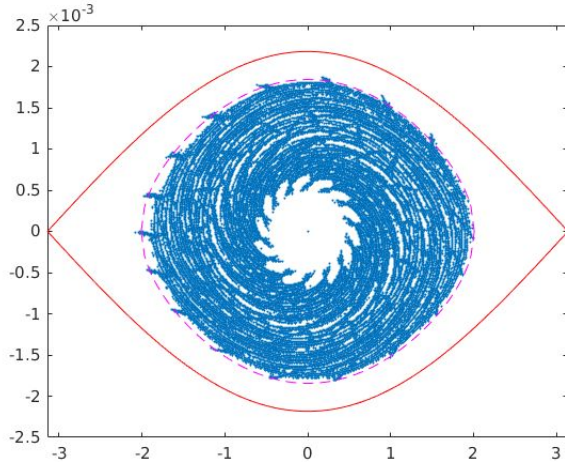
The buncher suppresses the energy spread very effectively. The energy spread is suppressed by an order of magnitude.

Momentum spread compensated by the buncher. The spread is reduced from $4.3e-4$ to $3.4e-5$.

Buncher Compensates Energy/Momentum Jitter As Well



With SC, 650 MHz Buncher at 185m, Off Energy Injection



Comments:

1. Reduced energy spread leaves margin between the beam distribution and separatrix
2. The off-energy injection scheme (CDR design) of the beam with a small energy spread can produce sharp charge density peaks near the central hole.

Linac beam parameters: $\text{std}(p) = 3.3875e-05$, 0.0 $\text{std}(dp/p)$ from jitter

Injection parameters: off energy, $dp/p_{inj} = 7e-4$, dp ripple = 0.0, one gate $-0.55\pi - 0.55\pi$

Simulated Results:

area of separatrix is 0.076627

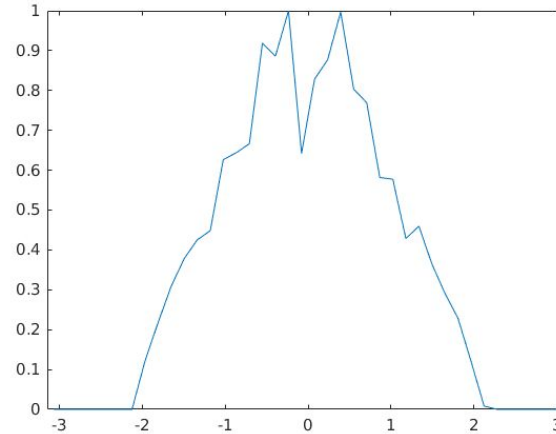
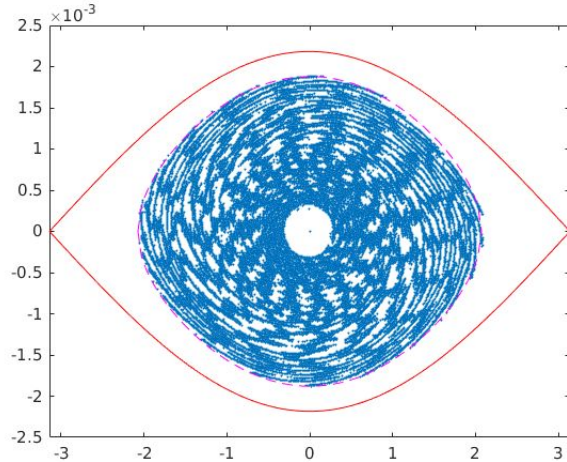
area of the 99.9% percent of particle is 0.048451, the ratio to the separatrix area is 0.632313

phase std 0.879742, energy std 1.033700

lost particles 0 out of 5410001 injected, ratio is 0.000000

bunching factor 3.193759

With SC, 650 MHz Buncher at 185m, On Energy Injection



Comments:
On-energy injection with two phase gates reduces the charge density peaks but keeps the longitudinal emittance small

Linac beam parameters: $\text{std}(p) = 3.3875e-05$, 0.0 $\text{std}(dp/p)$ from jitter

Injection parameters: on energy, $dp/p_{inj} = 0.0$, $dp \text{ ripple} = 0.0$

two gates $-0.65\text{Pi} - -0.1\text{Pi}$ and $0.1\text{Pi} - 0.65\text{Pi}$

Simulated Results:

area of separatrix is 0.076627

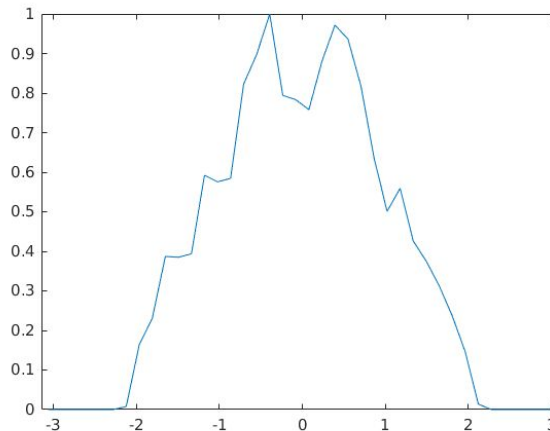
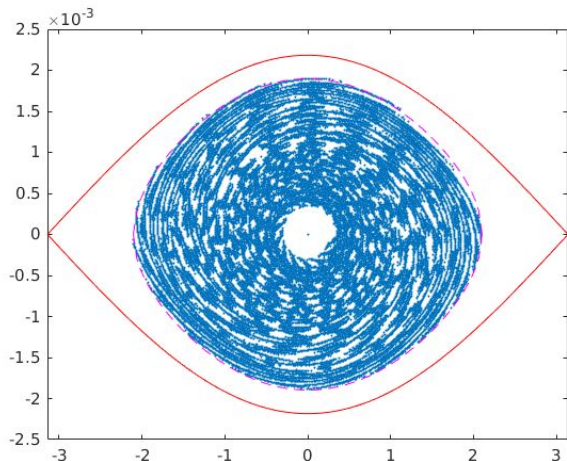
area of the 99.9% of particle is 0.050721, the ratio to the separatrix area is 0.661935

phase std 0.918701, energy std 1.047458

lost particles 0 out of 5420001 injected, ratio is 0.000000

bunching factor 2.736029

With SC, 650 MHz Buncher at 185m, Smaller Offset In Energy, Two Gates



Comments:

The injection scheme with a small energy offset and two phase gates reduces can deliver a more optimal initial distribution with a smaller peak density and emittance

Linac beam parameters: $\text{std}(p) = 3.3875e-05$, $0.0 \text{ std}(dp/p)$ from jitter

Injection parameters: off energy, $dp/p_{inj} = 2e-4$, $dp \text{ ripple} = 0.0$

two gates $-0.65\text{Pi} - -0.1\text{Pi}$ and $0.1\text{Pi} - 0.65\text{Pi}$

Simulated Results:

area of separatrix is 0.076627

area of the 99.9% of particle is 0.051846, the ratio to the separatrix area is 0.676616

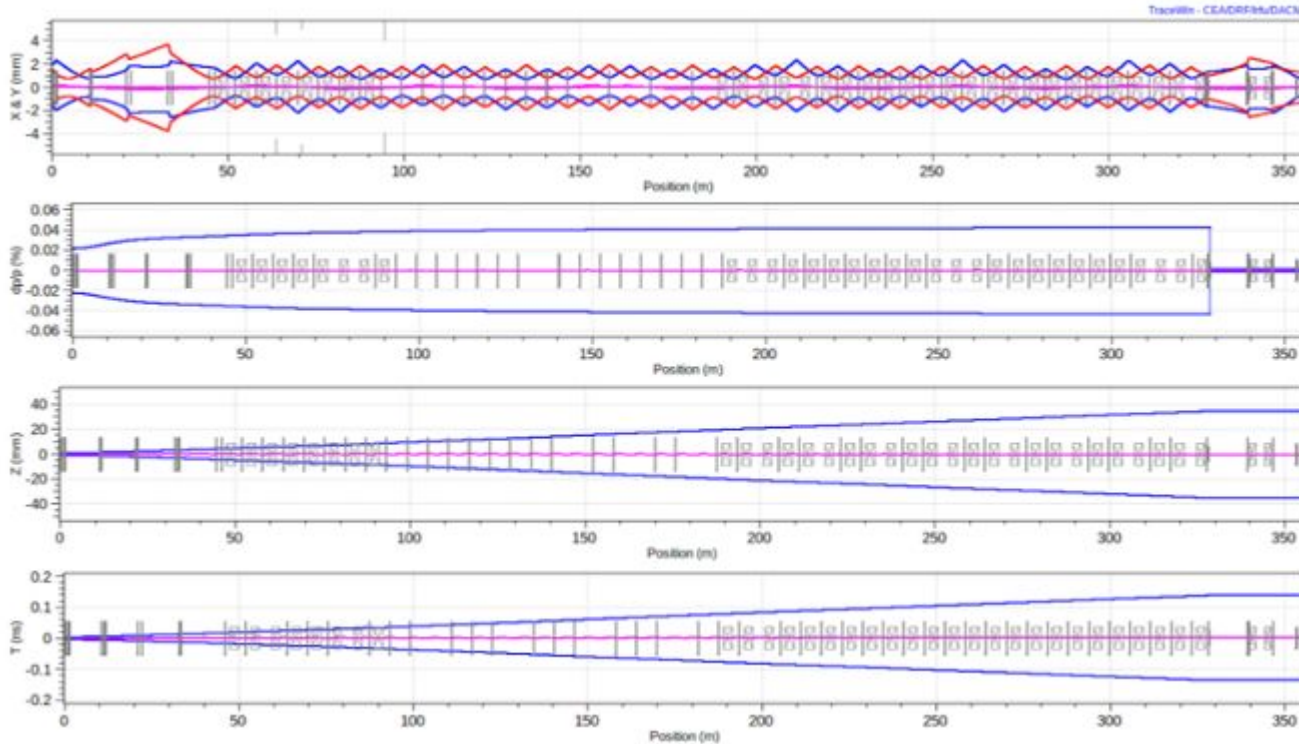
phase std 0.932859, energy std 1.058489

lost particles 0 out of 5420001 injected, ratio is 0.000000

bunching factor 2.633948

With SC and
Buncher at 325 m
(Location 2, end of BTL),
 $F=325$ MHz, $V=2$ MV

With SC, 325 MHz Buncher at 325 m, 2 MV



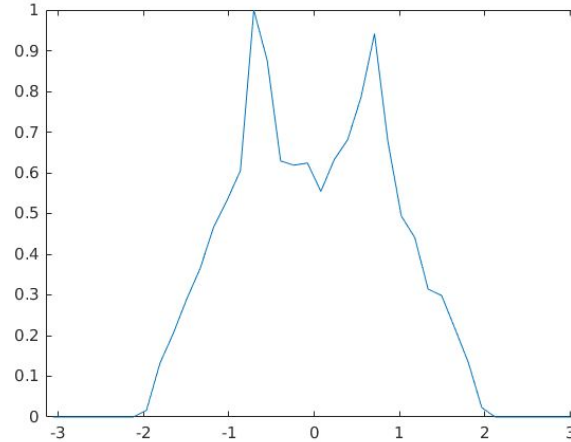
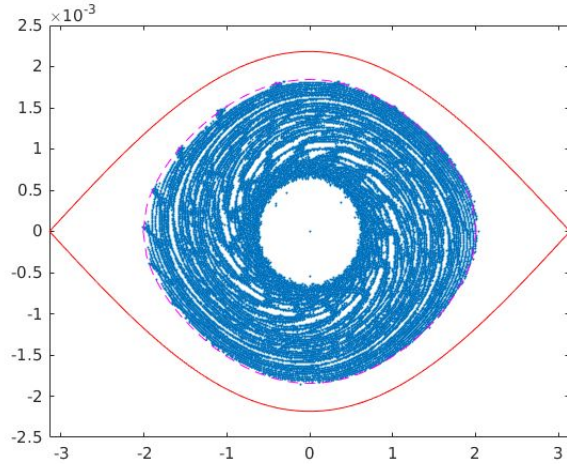
Comments:

- The buncher suppresses the energy spread very effectively. The energy spread is suppressed by an order of magnitude.
- The bunch length become somewhat long for 650 MHz although still acceptable.
- I selected a 325 MHz cavity instead of 650 MHz

Comments:

The results and conclusions for this energy spread compensation scheme are similar to those of the scheme with the 650 MHz buncher located at 185 m.

With SC, 325 MHz Buncher at 325 m, Off energy injection



Linac beam parameters: $\text{std}(p) = 1.1143\text{e-}05$, $0.0 \text{ std}(dp/p)$ from jitter

Injection parameters: off energy, $dp/p_{\text{inj}} = 7\text{e-}4$, dp ripple = 0.0, one gate -0.55π - 0.55π

Simulated Results:

area of separatrix is 0.076627

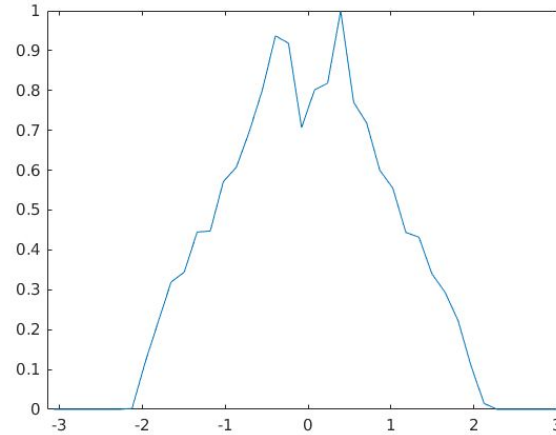
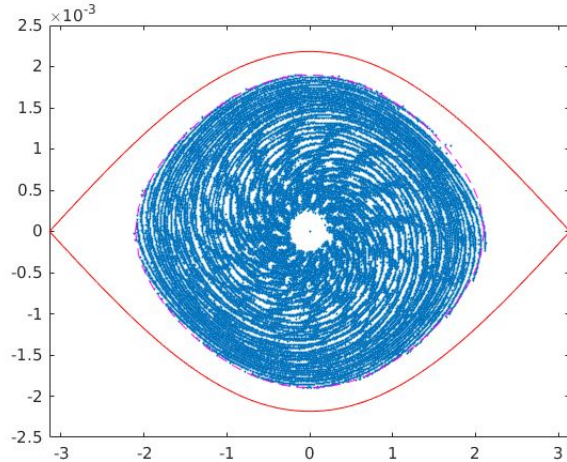
area of the 99.9% of particle is 0.048451, the ratio to the separatrix area is 0.632313

phase std 0.879647, energy std 1.033756

lost particles 0 out of 5410001 injected, ratio is 0.000000

bunching factor 3.186195

With SC, 325 MHz Buncher at 325 m, On energy injection



Linac beam parameters: $\text{std}(p) = 1.1143\text{e-}05$, 0.0 $\text{std}(dp/p)$ from jitter

Injection parameters: on energy, $dp/p_{\text{inj}} = 0.0$, dp ripple = 0.0

two gates -0.65Pi - -0.1Pi and 0.1Pi - 0.65Pi

Simulated Results:

area of separatrix is 0.076627

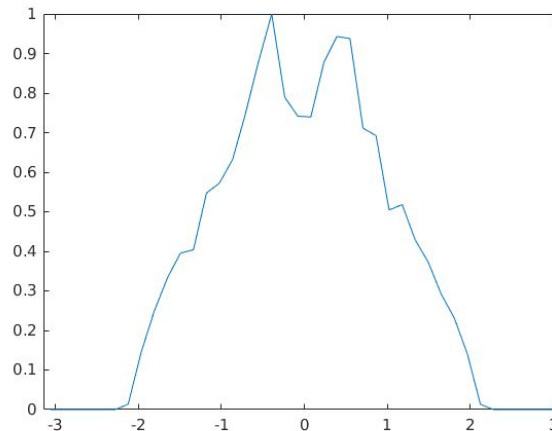
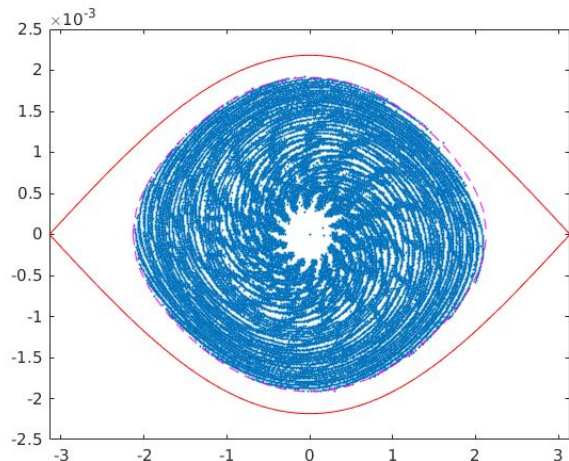
area of the 99.9% of particle is 0.051846, the ratio to the separatrix area is 0.676616

phase std 0.918726, energy std 1.047091

lost particles 0 out of 5420001 injected, ratio is 0.000000

bunching factor 2.805933

With SC, 650 MHz Buncher at 185m, Smaller Offset In Energy, Two Phase Gates



Linac beam parameters: $\text{std}(p) = 1.1143\text{e-}05$, 0.0 $\text{std}(dp/p)$ from jitter

Injection parameters: off energy, $dp/p_{inj} = 2.0\text{e-}4$, dp ripple = 0.0

two gates -0.65Pi - -0.1Pi and 0.1Pi - 0.65Pi

Simulated Results:

area of separatrix is 0.076627

area of the 99.9 of particle is 0.052963, the ratio to the separatrix area is 0.691193

phase std 0.932499, energy std 1.058671

lost particles 0 out of 5420001 injected, ratio is 0.000000

bunching factor 2.692723

Summary: Off-Energy Injection

Injection energy offset $dp/p_{inj} = 7e-4$, one gate $-0.55\pi - 0.55\pi$

Parameter	Baseline, no SC	Baseline, with SC	650 MHz @ 185 m	325 MHz @ 325 m
Linac dp/p + Jitter, r.m.s. after buncher	$2.17e-04 + 1.5e-04$	$4.33e-04 + 1.5e-04$	$3.3875e-05$	$1.1143e-05$
Ratio 99.9% to separatrix size	0.86	0.98	0.63	0.63
Phase / Energy r.m.s. size	0.91 / 1.05	0.98 / 1.08	0.88 / 1.03	0.88 / 1.03
Lost / Injected particles	1836 / $5.41e6$	33930 / $5.41e6$	0 / $5.41e6$	0 / $5.41e6$
Bunching factor	2.56	2.24	3.19	3.19

Summary: On-Energy Injection

Injection energy offset $dp/p_{inj} = 0.0$, dp ripple = 0.0, two gates -0.65π - -0.1π and 0.1π - 0.65π

Parameter	Baseline, no SC	Baseline, with SC	650 MHz @ 185 m	325 MHz @ 325 m
Linac dp/p + Jitter, r.m.s. after buncher	$2.17e-04 + 1.5e-04$	$4.33e-04 + 1.5e-04$	$3.39e-05$	$1.11e-05$
Ratio 99.9% to separatrix size	0.75	0.88	0.66	0.68
Phase / Energy r.m.s. size	0.94 / 1.06	0.99 / 1.11	0.92 / 1.05	0.92 / 1.05
Lost / Injected particles	85 / 5.42e6	520 / 5.42e6	0 / 5.42e6	0 / 5.42e6
Bunching factor	2.67	2.30	2.74	2.81

Summary: Off-energy injection with a small energy offset and two phase gates

Injection energy offset $dp/p_{inj} = 2.0e-4$, dp ripple = 0.0, two gates -0.65π - -0.1π and 0.1π - 0.65π

Parameter	Baseline, no SC	Baseline, with SC	650 MHz @ 185 m	325 MHz @ 325 m
Linac dp/p + Jitter, r.m.s. after buncher	$2.17e-04 + 1.5e-04$	$4.33e-04 + 1.5e-04$	$3.3875e-05$	$1.1143e-05$
Ratio 99.9% to separatrix size	—	—	0.68	0.69
Phase / Energy r.m.s. size	—	—	0.93 / 1.06	0.93 / 1.06
Lost / Injected particles	—	—	0 / $5.42e6$	0 / $5.42e6$
Bunching factor	—	—	2.63	2.69

Summary [1]

The CDR design did not include the growth of the energy spread driven by the space charge.

The space charge doubles the energy spread after the linac in roughly ~70m. The increased energy spread leads to a larger beam emittance and beam losses.

On-energy injection with two gates helps but only marginally. It also increases the number of foil hits by ~50%.

A buncher located in BTL can reduce the energy spread and beam jitter by an order of magnitude. A drift after the linac is required to convert the non-correlated energy spread to correlated one that can be removed by the buncher.

Summary [2]

Reduction of the energy spread of the beam injected into Booster reduces the emittance of the Booster painted beam, leaving a clear margin between the beam and the speratrix.

Off-energy, one-gate injection of the beam with a small emittance can lead to an increased peak charge density. On energy injection with two phase gates mitigates this effect. Simulations indicated that injection with a small energy offset and two phase gates might be optimal.

Although reducing the energy spread helps to reduce the emittance of the Booster beam, minimizing the energy spread to a very small number might not be optimal as it can lead to increased charge density and space charge tune shift.

Conclusions

Not controlling the energy spread in the BTL will lead to filling in the Booster beam bucket and losses at the injection comparable to 0.5%-1%

A buncher situated in BTL can be used to control the energy spread, leaving a margin between the painted beam distribution and the separatrix clear of particles.

A very small energy spread can result in local charge density peaks and might not be optimal. The energy spread and injection parameters (energy offset and injection phase windows) can be optimized to obtain optimal injected Booster distribution as shown in this presentation.

Addendum
Losses from Booster Bucket
During Accelerations

Description of these Studies

Simulate acceleration in the Booster and beam losses during acceleration for two different distributions:

- Without energy compensation (no buncher), off energy injection (**Slide 11**)
- With compensation of the energy spread using the buncher in BTL (**Slide 16**)

Try several different voltage ramp curves: slower and faster

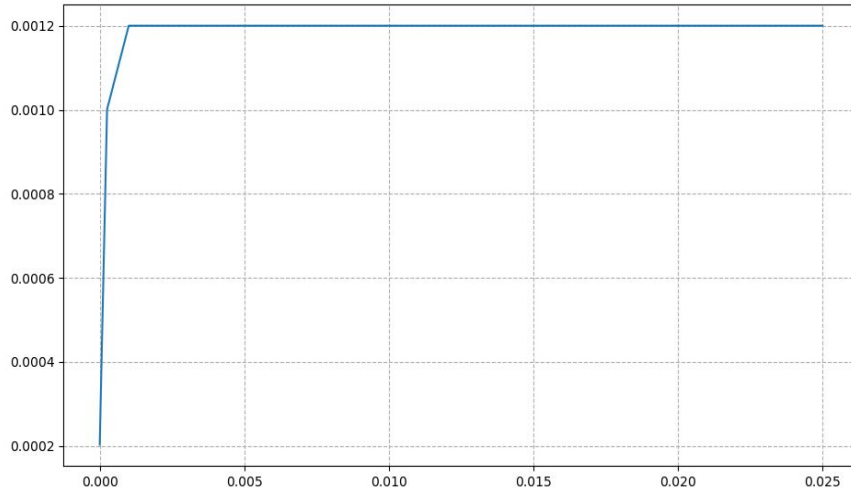
Two codes used:

- PyOrbit with the SC, impedances, transition crossing (J.-F. Ostiguy)
- My nameless Python code, no SC, no impedances, stopped before transition crossing

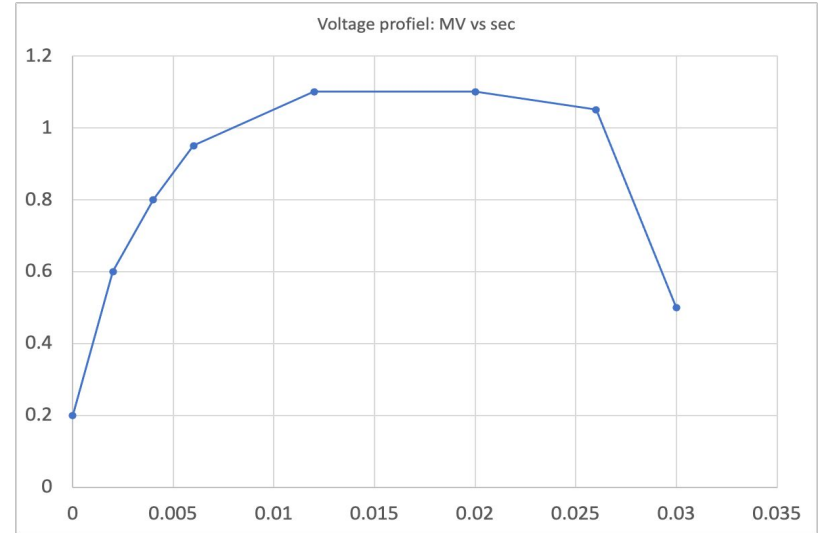
Voltage Profiles

Two Voltage curves used

Fast



Slow



Without energy compensation (see Slide 11)

PyOrbit

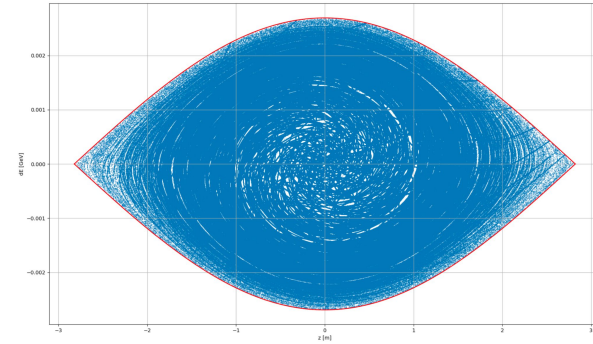
- Simulations: 500k particles, with SC, Impedance
- Only fast voltage was simulated
- **Relative Particle loss after 500 turns 1.3e-4**

My simplified code

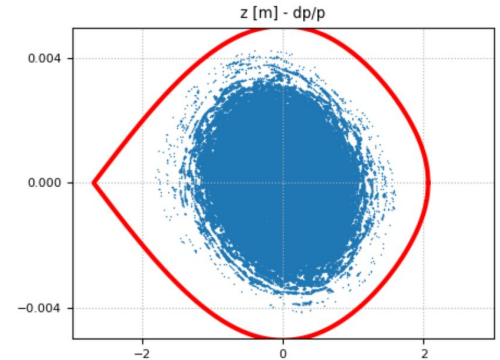
- Simulations: 5.3M particles, No SC, no impedance
- Particle losses:
 - **Fast voltage ramp: zero losses after 3000 turns**
 - **Slow voltage ramp: 0.7% particles lost after 500 turns**

Something to worry about: Larger emittance at transition for both cases, simulated with Lee-Tang Gamma_t jump

Initial



After 500 turns



With Energy Spread Compensation (See slide 16)

PyOrbit

- Not simulated

My simplified Python code

- Simulations: 5.3M particles, No SC, no impedance
- Particle losses:
 - **Fast voltage ramp: zero losses**
 - **Slow voltage ramp: zero losses**

Addendum Conclusion

Losses at acceleration will depend on the ramp rate of the voltage. Fast growing voltage at the slow acceleration (magnetic field variation at the bottom of the sine curve) will stabilize and move particles away from separatrix.

Large energy spread still can cause losses at injection due to particles missing the speratrix. Losses can reach a percent-ish level. Control of energy spread still can be beneficial.

Injection with a reduced energy spread will generate the beam with a smaller longitudinal emittance that can reduce losses at γ_t .

Backup Slide: Loss Requirements (Rough Estimate)

PIP-II will inject 17.6 kW of beam power into Booster

2% loss at injection will provide 350 W beam loss in Booster

0.2% loss at transition will provide additional 200 W loss in Booster

Combined these losses will add up to 1 W/m losses - roughly the loss limit

These considerations do not include collimators into account